

Introduction to Semiconductor Integrated Optics

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Contents

Acknowledgments	xv
Preface	xvii
Introduction	xix
Chapter 1 Basic Electromagnetics	1
1.1 General Relationships	1
1.1.1 Maxwell's Equations	1
1.1.2 Current Continuity	2
1.1.3 The Wave Equation	3
1.1.4 TEM Waves and Polarization	4
1.2 Solving the Wave Equation	4
1.2.1 Propagation Constant	6
1.2.2 Maxwell for Sinusoidal Fields	7
1.3 Energy	8
1.3.1 Poynting Vector	9
1.4 Interference	10
Chapter 2 A Summary of Semiconductors	13
2.1 Silicon and Gallium Arsenide	13
2.1.1 Crystalline Properties	14
2.1.2 Miller Indices and Atomic Planes	16
2.2 Energy Bands	17
2.2.1 Band Structure Calculations	18
2.2.2 Energy Bands	19
2.2.3 Electron Transitions between Bands	20
2.2.4 Effective Mass	21
2.3 Carrier Concentration	24
2.3.1 Density of States	24
2.3.2 Fermi-Dirac Distribution	25

2.3.3	Intrinsic Carrier Concentration	2
2.4	Doping	3
2.4.1	Donors and Acceptors	3
2.4.2	Fermi Level Determination	3
2.4.3	Degenerate Semiconductors	3
2.5	Transport	3
2.5.1	Drift and Diffusion	3
2.5.2	Contributions to Mobility	3
2.5.3	High Field Effects	3
2.6	The PN Junction	3
2.6.1	The Depletion Approximation	4
2.6.2	Debye Length	4
2.6.3	The PN Junction Under Bias	4
2.6.4	Reverse Bias Breakdown	4
2.6.5	Junction Capacitance	4
2.6.6	The P-I-N Diode	4
2.7	Heterojunctions and Quantum Wells	4
2.7.1	Single and Double Heterostructures	4
2.7.2	Quantum Wells	4
Chapter 3	Optical Properties of Semiconductors	5
3.1	Refractive Index	5
3.2	Absorption	5
3.2.1	Direct Bandgap	5
3.2.2	Indirect Bandgap	5
3.2.3	Band Tails	6
3.2.4	Free Carrier Absorption	6
3.2.5	Franz-Keldysh Effect	6
3.3	Recombination	6
3.3.1	Radiative Transitions	6
3.3.2	Direct and Indirect Transitions	6
3.3.3	Nonradiative Recombination	6
3.4	Polarization	6
3.4.1	Susceptibility	6
3.4.2	Polarization Model	6
3.5	Complex Material Constants	6
3.5.1	Complex Dielectric Constant	6
3.5.2	Complex Refractive Index	7
3.5.3	Complex Propagation Constant	7
3.5.4	Summary of Complexities	7
3.6	Dielectric Tensor	7
3.7	Kramers-Kronig Relations	7

Chapter 4	Optical Semiconductor Materials	77
4.1	III-V Materials	77
4.1.1	The III-V Extended Family	77
4.1.2	Regimes of Application	79
4.2	Composition and Optical Properties	81
4.2.1	Refractive Index	81
4.2.2	Energy Gap	83
4.3	Bulk Crystal Growth	84
4.3.1	Liquid-Encapsulated Czochralski	86
4.3.2	Horizontal Bridgman and Vertical Gradient Freeze	87
4.3.3	Wafer Sawing and Flat Grinding	88
4.4	Epitaxial Layer Growth	89
4.4.1	Liquid Phase Epitaxy	90
4.4.2	Molecular Beam Epitaxy	90
4.4.3	Metalorganic Chemical Vapor Deposition	92
4.5	More Optical Materials	94
4.5.1	Silicon	94
4.5.2	Silicon: Modifications and Accessories	95
4.5.3	Silicon/Germanium	96
4.5.4	Other Compound Semiconductors	96
Chapter 5	Basics of Semiconductor Processing	99
5.1	A Typical Optoelectronic Process	100
5.1.1	The Basics	100
5.1.2	The Embellishments	102
5.1.3	The Environment	103
5.2	Photolithography	103
5.2.1	Masks	104
5.2.2	Photoresist	104
5.2.3	Lift-Off and Image Reversal	107
5.2.4	Mask Aligners	107
5.2.5	Nonoptical Lithography	109
5.3	Etching	109
5.3.1	Dry Etching Basics and Machinery	110
5.3.2	Etch Gasses	114
5.3.3	Problems and Limitations	114
5.3.4	Wet Etching	115
5.4	Dielectrics	117
5.4.1	Plasma Deposition	117
5.4.2	Chemical Vapor Deposition	118
5.5	Metals	119
5.6	Processing Varia	120

5.6.1	III-V Post-Processing	12
5.6.2	Ion Implantation	12
5.6.3	Rapid Thermal Annealing	12
Chapter 6	Reflections at Boundaries	12
6.1	Angles of Reflection and Refraction	12
6.2	Boundary Conditions of Electromagnetic Fields	12
6.3	Reflection and Transmission Coefficients	12
6.3.1	TE Configuration	12
6.3.2	TM Configuration	13
6.3.3	Power Transmission and Reflection	13
6.4	Two Special Cases	13
6.4.1	Normal Incidence	13
6.4.2	Total Internal Reflection	13
Chapter 7	Guided Waves and Slab Waveguides	14
7.1	Perfect Mirror Waveguides	14
7.1.1	Discrete Waveguide Modes	14
7.1.2	Propagation Constants and Effective Index	14
7.2	Dielectric Waveguides: the Ray Optic Model	15
7.2.1	Total Internal Reflection	15
7.2.2	Symmetric Waveguides	15
7.2.3	Monomode Conditions	15
7.2.4	Propagation Constants and Effective Index, Again	15
7.2.5	Asymmetric Waveguides	15
7.3	Electromagnetic Model	16
7.3.1	Eigenvalue Equation for a Slab Waveguide	16
7.3.2	Propagating and Decaying Solutions	16
7.3.3	Propagation and Decay Constants	16
7.4	Dielectric Waveguides: Electric and Magnetic Fields	16
7.4.1	Field Solutions	16
7.4.2	Power Normalization	16
7.4.3	Symmetric Waveguide: Cutoff Condition	16
7.4.4	Asymmetric Waveguide: Cutoff Condition	17
7.4.5	Confinement Factor	17
7.5	Goos-Hänchen Shift	17
Chapter 8	Optical Channel Waveguides	17
8.1	Two-Dimensional Waveguide Structures	17
8.1.1	Etched Structures	17
8.1.2	Other III-V Waveguide Techniques	17
8.1.3	Silicon-Based Waveguides	17
8.2	Two-Dimensional Waveguide Analysis	18

8.2.1	Effective Index Approximation	183
8.2.2	Method of Field Shadows	186
8.2.3	Waveguide Modes	188
8.2.4	Monomode Waveguides	189
8.2.5	Lateral Waveguiding Mechanisms	191
8.3	Input/Output Coupling	193
8.3.1	Butt Coupling	193
8.3.2	End-Fire Coupling	194
8.3.3	Grating Coupling	195
8.3.4	Prism Couplers	196
8.4	Waveguide Losses	197
8.4.1	Band-Edge Absorption	197
8.4.2	Free-Carrier Absorption	198
8.4.3	Scattering	199
8.4.4	Radiation Losses	200
8.4.5	Typical Loss Values	201
8.5	Loss Characterization	201
8.5.1	Cut-Back Technique	202
8.5.2	Fabry-Perot Resonances	202
8.6	Passive Waveguide Structures	204
8.6.1	Curves	204
8.6.2	Couplers	207
8.6.3	Y-Junctions	209
Chapter 9	Lasers	215
9.1	Laser Operation—A Quick Heuristic Discussion	216
9.2	Photon Emission in Semiconductors	217
9.2.1	Spontaneous and Stimulated Emission	217
9.2.2	Electron Distribution and Transition Rates	218
9.2.3	Lineshape Function	220
9.2.4	Spectral Shape and Broadening	222
9.3	Optical Gain	223
9.3.1	Amplification and Attenuation	224
9.3.2	Semiconductor Gain	225
9.3.3	Gain Saturation	228
9.3.4	Hole Burning	231
9.4	Laser Oscillation	232
9.4.1	Fabry-Perot Etalon	232
9.4.2	The Etalon with Optical Gain	236
9.4.3	Laser Resonance	239
9.5	Semiconductor Laser Structures	239
9.5.1	Materials and Heterostructures	239

9.5.2	Quantum-Well Lasers	24
9.5.3	Typical Laser Designs	24
9.5.4	Reliability and Lifetime	24
9.6	Electrical and Optical Characterization	24
9.6.1	Threshold Current	24
9.6.2	Output Power and Efficiency	25
9.6.3	Spectrum	25
9.6.4	Spatial Intensity Distribution	25
9.6.5	Temperature Variations	25
9.7	Light-Emitting Diodes	25
9.8	Distributed Feedback Lasers	25
9.8.1	Distributed Feedback	25
9.8.2	DBR/DFB Fabrication	26
9.8.3	Operation and Special Features	26
9.9	Surface-Emitting Lasers	26
9.9.1	Mirror Deflectors	26
9.9.2	Surface Grating Couplers	26
9.9.3	VCSELs	26
Chapter 10	Photodetectors	27
10.1	General Principles	27
10.1.1	Photon to Electron Conversion	27
10.1.2	Efficiency	27
10.1.3	Noise	27
10.2	Semiconductor Detector Materials	27
10.3	The P-I-N Photodiode	27
10.3.1	Waveguide Detector	27
10.3.2	Surface Detector	28
10.4	Schottky and MSM Detectors	28
10.4.1	Schottky Barrier	28
10.4.2	MSM Detector	28
10.4.3	Surface Illumination	28
10.5	Avalanche Photodiodes	28
10.5.1	Avalanche Multiplication	28
10.5.2	Photodetector Structure	28
Chapter 11	Modulators	29
11.1	Phase and Intensity Modulation	29
11.2	Modulator Structures: a Brief Survey	29
11.2.1	Electro-Optic Effects	29
11.2.2	Directional Couplers	29
11.2.3	Total Internal Reflection Deflectors	29
11.2.4	Bragg Gratings	29

11.2.5	Surface Acoustic Wave Devices	297
11.2.6	Interferometric Modulators	299
11.2.7	Traveling Wave Modulators	299
11.2.8	Mechanical Beam Steering	299
11.3	Electro-Optics	300
11.3.1	Pockels Effect	300
11.3.2	Kerr Effect	301
11.3.3	Franz-Keldysh Effect	302
11.3.4	Plasma Effects	304
11.3.5	Silicon Electro-Optics	305
11.4	Quantum-Well Modulators	306
11.4.1	Quantum-Confined Stark Effect	306
11.4.2	Electrorefraction in Quantum Wells	308
11.4.3	Chirp	310
11.4.4	Quantum-Well Modulator Structures	311
11.5	Interferometric Modulators	312
11.5.1	Output Characteristics	313
11.5.2	Interferometer Modulator Performance	315
11.5.3	Other Origins for Phase Shift	315
Chapter 12	Hybridization and Monolithic Integration	321
12.1	Integration versus Hybridization	322
12.1.1	Examples: Photonic Integration	323
12.1.2	Examples: Electronics Integration	326
12.1.3	Examples: Hybridization	326
12.2	Waveguide-Based Integration	328
12.2.1	Evanescence and Butt Coupling	328
12.2.2	Selective Growth	331
12.2.3	Quantum-Well Intermixing	332
12.2.4	Electrical Isolation	334
12.3	Monolithic Devices and Systems	334
12.3.1	Other Integratable Device Structures	335
12.3.2	Monolithic System Implementations	338
12.4	Hybrid Optical Systems	338
12.4.1	Alignment	339
12.4.2	Bonding	340
12.4.3	Heteroepitaxy	342
Appendix A	List of Variables	349
Appendix B	List of Useful Physical Constants	357
About the Author		359
Index		361